

# SKKT 71, SKKH 71



## SEMIPACK<sup>®</sup> 1

### Thyristor / Diode Modules

SKKT 71

SKKH 71

#### Features

- Heat transfer through aluminium oxide ceramic isolated metal baseplate
- Hard soldered joints for high reliability
- UL recognized, file no. E 63 532

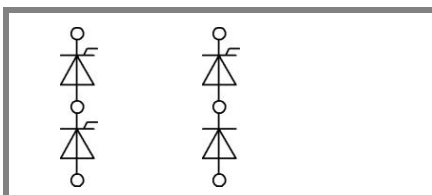
#### Typical Applications

- DC motor control (e. g. for machine tools)
- AC motor soft starters
- Temperature control (e. g. for ovens, chemical processes)
- Professional light dimming (studios, theaters)

1) See the assembly instructions

$V_{RSM}$ V	$V_{RRM}, V_{DRM}$ V	$I_{TRMS} = 125$ A (maximum value for continuous operation) $I_{TAV} = 70$ A (sin. 180; $T_c = 85$ °C)	
700	600	SKKT 71/06E	
900	800	SKKT 71/08E	SKKH 71/08D
1300	1200	SKKT 71/12E	SKKH 71/12E
1500	1400	SKKT 71/14E	SKKH 71/14E
1700	1600	SKKT 71/16E	SKKH 71/16E
1900	1800	SKKT 71/18E	SKKH 71/18E

Symbol	Conditions	Values	Units
$I_{TAV}$	sin. 180; $T_c = 85$ (100) °C;	70 (50)	A
$I_D$	P3/180; $T_a = 45$ °C; B2 / B6	62 / 75	A
	P3/180F; $T_a = 35$ °C; B2 / B6	115 / 145	A
$I_{RMS}$	P3/180F; $T_a = 45$ °C; W1 / W3	155 / 3 * 115	A
$I_{TSM}$	$T_{vj} = 25$ °C; 10 ms	1600	A
	$T_{vj} = 125$ °C; 10 ms	1450	A
$i^2t$	$T_{vj} = 25$ °C; 8,3 ... 10 ms	13000	A <sup>2</sup> s
	$T_{vj} = 125$ °C; 8,3 ... 10 ms	10500	A <sup>2</sup> s
$V_T$	$T_{vj} = 25$ °C; $I_T = 300$ A	max. 1,9	V
$V_{T(TO)}$	$T_{vj} = 125$ °C	max. 0,9	V
$r_T$	$T_{vj} = 125$ °C	max. 3,5	mΩ
$I_{DD}, I_{RD}$	$T_{vj} = 125$ °C; $V_{RD} = V_{RRM}; V_{DD} = V_{DRM}$	max. 20	mA
$t_{gd}$	$T_{vj} = 25$ °C; $I_G = 1$ A; $di_G/dt = 1$ A/μs	1	μs
$t_{gr}$	$V_D = 0,67 * V_{DRM}$	1	μs
$(di/dt)_{cr}$	$T_{vj} = 125$ °C	max. 150	A/μs
$(dv/dt)_{cr}$	$T_{vj} = 125$ °C; SKK ...D / SKK ...E	max. 500 / 1000	V/μs
$t_q$	$T_{vj} = 125$ °C,	80	μs
$I_H$	$T_{vj} = 25$ °C; typ. / max.	150 / 250	mA
$I_L$	$T_{vj} = 25$ °C; $R_G = 33$ Ω; typ. / max.	300 / 600	mA
$V_{GT}$	$T_{vj} = 25$ °C; d.c.	min. 3	V
$I_{GT}$	$T_{vj} = 25$ °C; d.c.	min. 150	mA
$V_{GD}$	$T_{vj} = 125$ °C; d.c.	max. 0,25	V
$I_{GD}$	$T_{vj} = 125$ °C; d.c.	max. 6	mA
$R_{th(j-c)}$	cont.; per thyristor / per module	0,35 / 0,18	K/W
$R_{th(j-c)}$	sin. 180; per thyristor / per module	0,37 / 0,19	K/W
$R_{th(j-c)}$	rec. 120; per thyristor / per module	0,39 / 0,2	K/W
$R_{th(c-s)}$	per thyristor / per module	0,2 / 0,1	K/W
$T_{vj}$		- 40 ... + 125	°C
$T_{stg}$		- 40 ... + 125	°C
$V_{isol}$	a. c. 50 Hz; r.m.s.; 1 s / 1 min.	3600 / 3000	V~
$M_s$	to heatsink	5 ± 15 % <sup>1)</sup>	Nm
$M_t$	to terminals	3 ± 15 %	Nm
$a$		5 * 9,81	m/s <sup>2</sup>
$m$	approx.	95	g
Case	SKKT	A 5	
	SKKH	A 6	



SKKT

SKKH

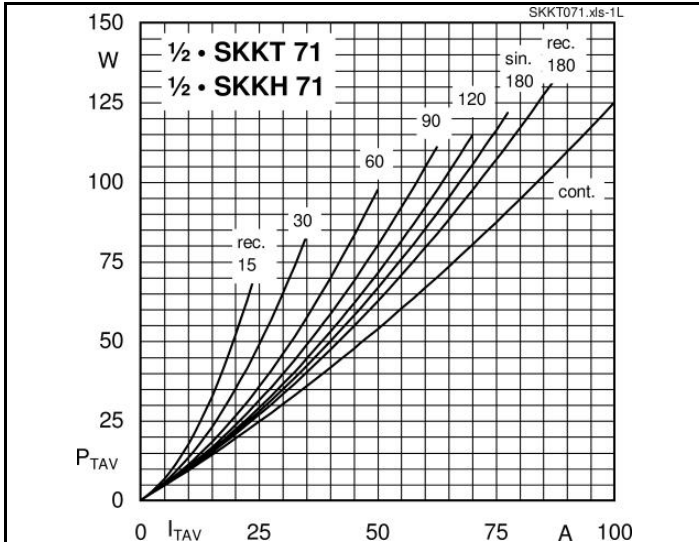


Fig. 1L Power dissipation per thyristor vs. on-state current

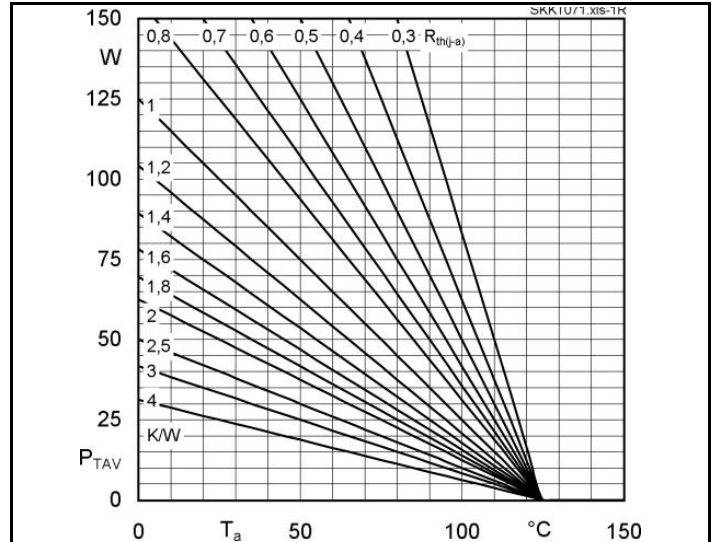


Fig. 1R Power dissipation per thyristor vs. ambient temp.

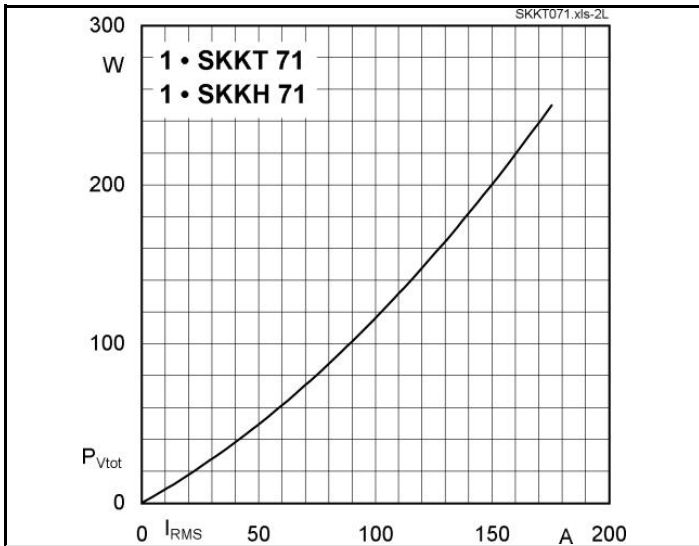


Fig. 2L Power dissipation per module vs. rms current

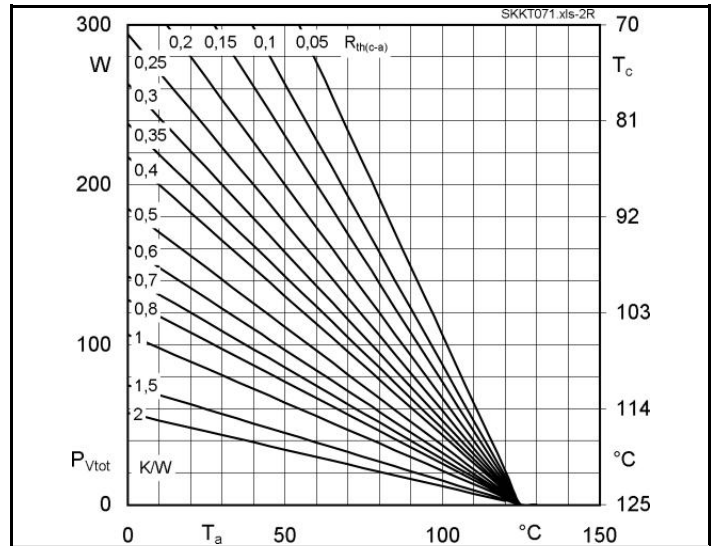


Fig. 2R Power dissipation per module vs. case temp.

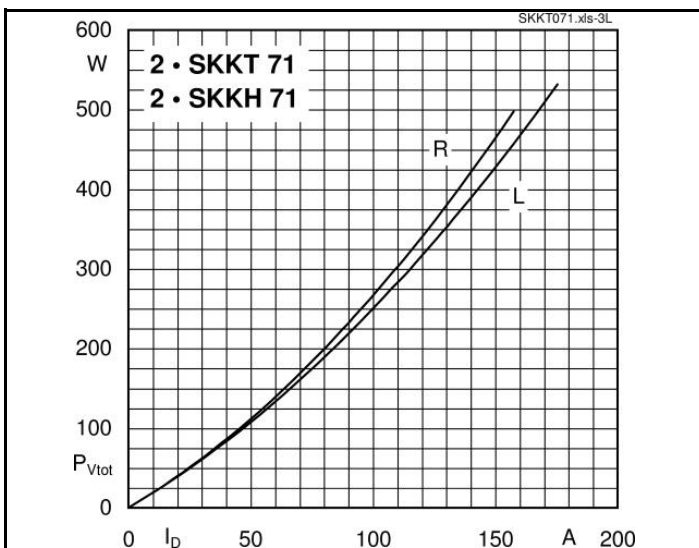


Fig. 3L Power dissipation of two modules vs. direct current

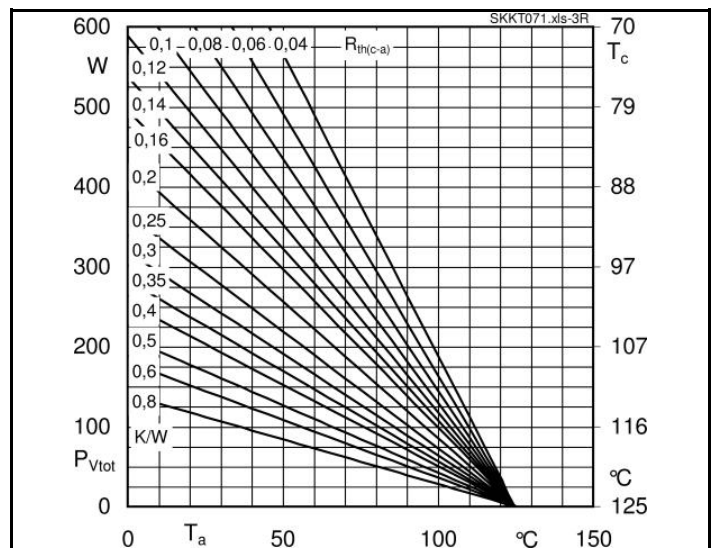
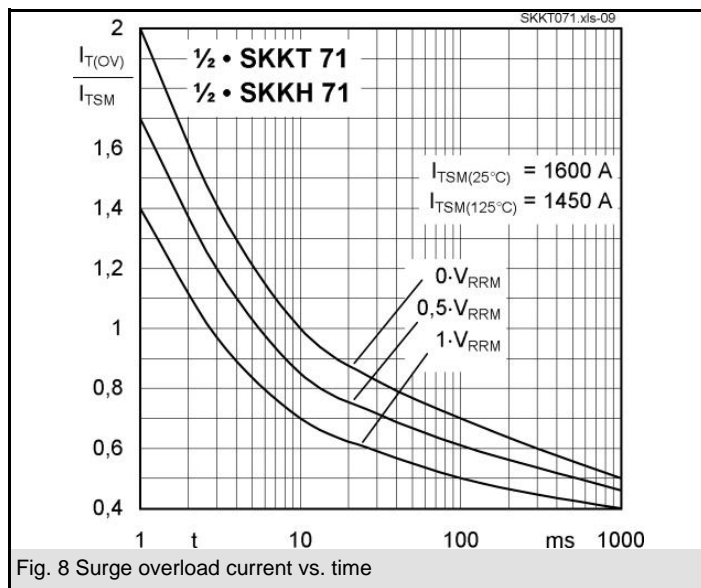
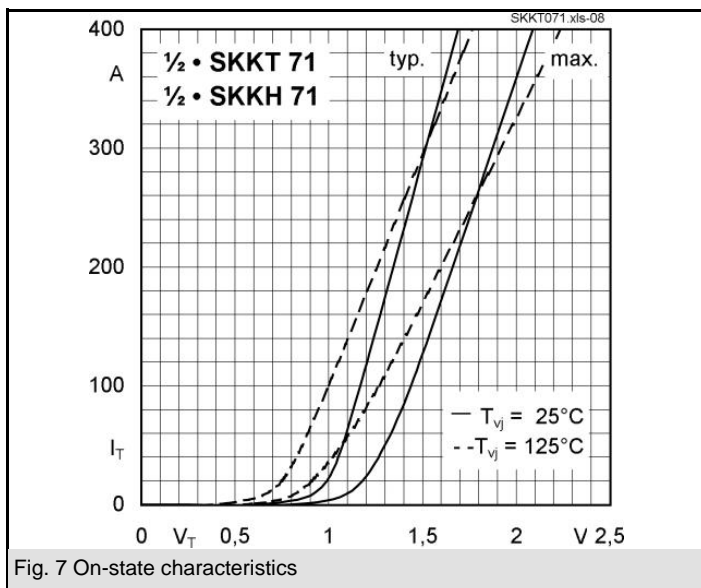
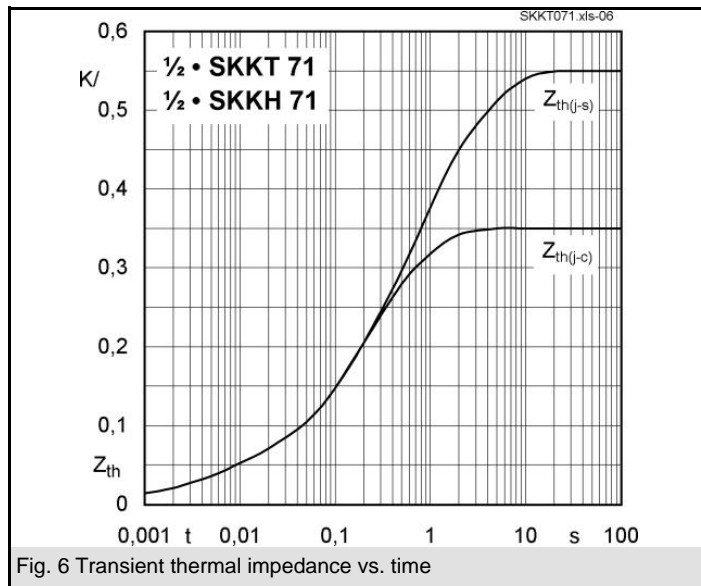
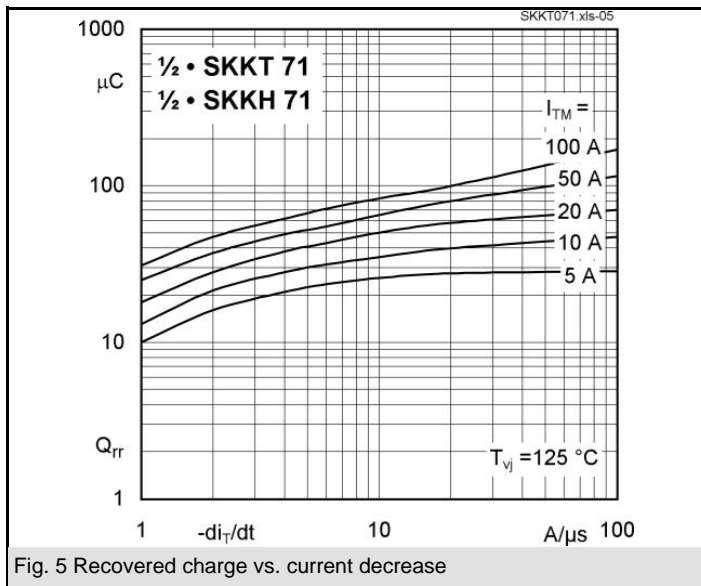
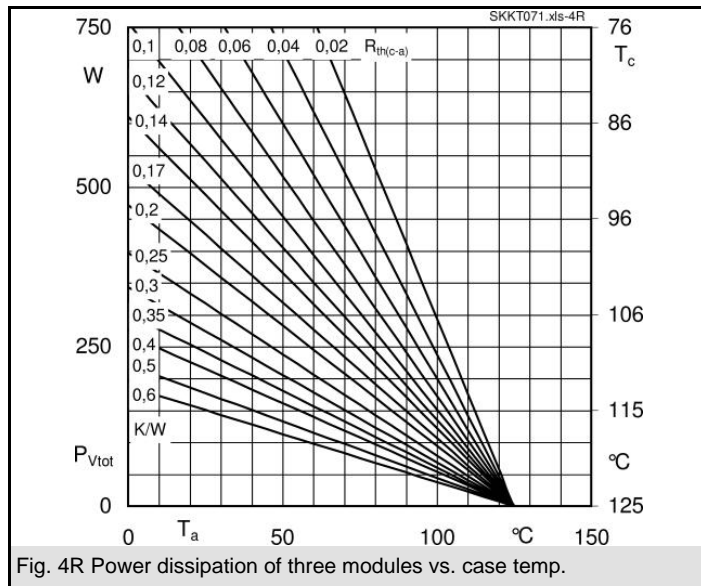
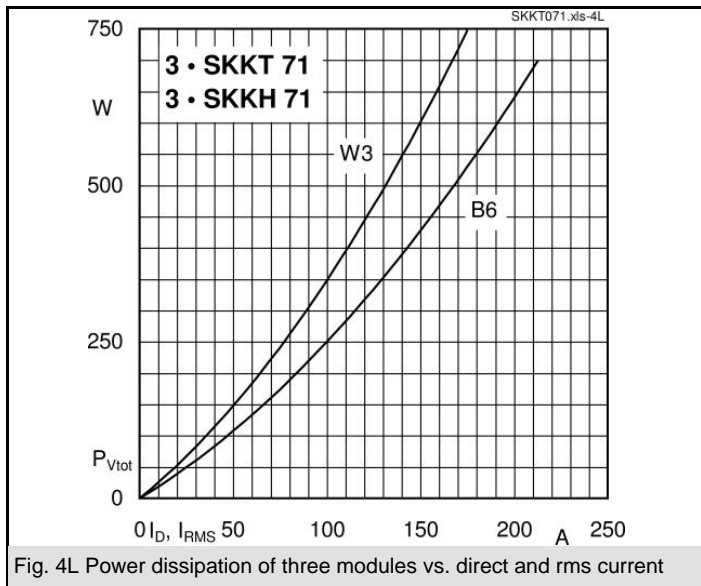


Fig. 3R Power dissipation of two modules vs. case temp.

# SKKT 71, SKKH 71



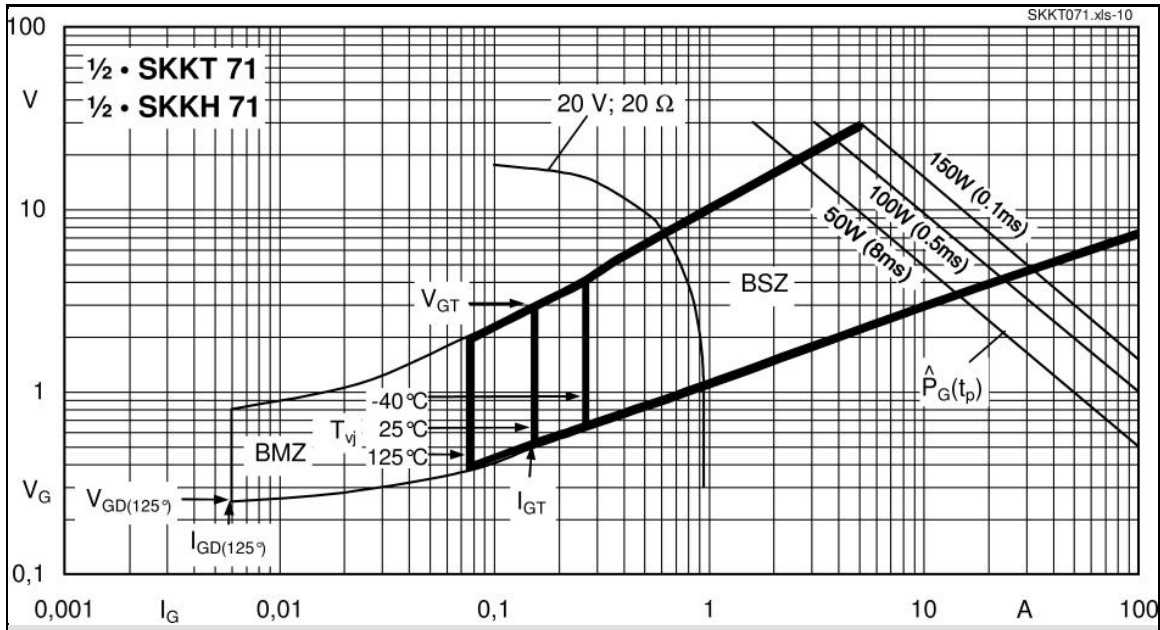
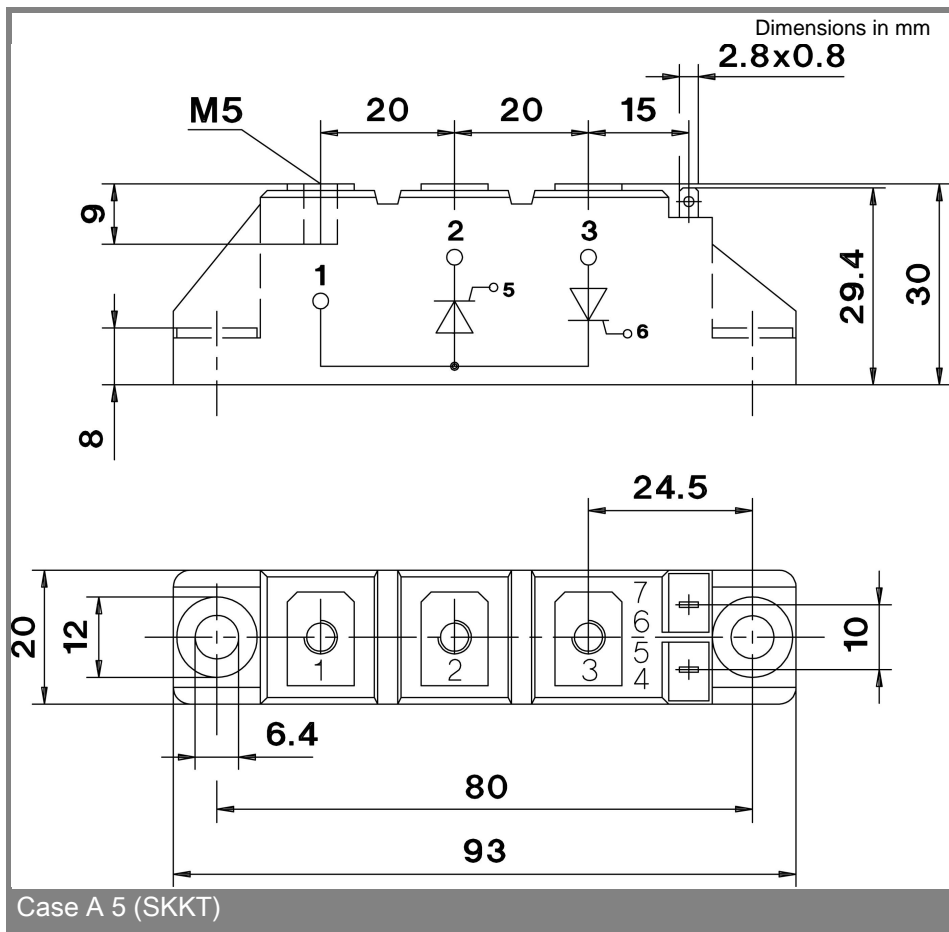
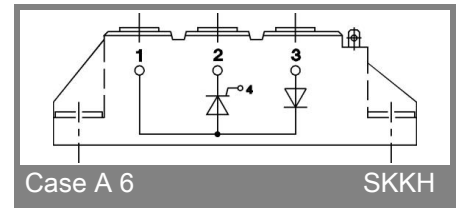


Fig. 9 Gate trigger characteristics



Case A 5 (SKKT)



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